NSN 5961-01-334-8647

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-334-8647 **Inclosure Material:** Glass **Overall Length:** 0.300 inches **Terminal Length:** 0.975 inches **Overall Diameter:** 0.104 inches **Function For Which Designed:** Switching **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 reverse voltage, peak **Current Rating Per Characteristic:** 10.00 microamperes forward current, average peak **Power Rating Per Characteristic:** 300.0 milliwatts small-signal input power, common-collector preset **Capacitance Rating In Picofarads:** 1.8 **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Test Data Document:** 50027-9999-4408 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**